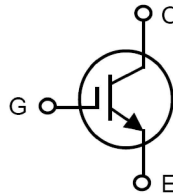


# 1200V XPT™ GenX4™ IGBT

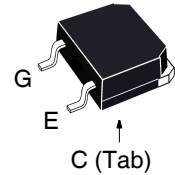
# IXYT55N120A4HV

$V_{CES} = 1200V$   
 $I_{C110} = 55A$   
 $V_{CE(sat)} \leq 1.8V$   
 $t_{fi(typ)} = 270ns$

Ultra Low-Vsat PT IGBT for  
up to 5kHz Switching



TO-268HV  
(IXYT..HV)



G = Gate      C = Collector  
 E = Emitter    Tab = Collector

| Symbol                        | Test Conditions   | Maximum Ratings                                   |            |
|-------------------------------|---|---|------------|
| $V_{CES}$                     | $T_J = 25^\circ C$ to $175^\circ C$   | 1200  | V          |
| $V_{CGR}$                     | $T_J = 25^\circ C$ to $175^\circ C$ , $R_{GE} = 1M\Omega$                           | 1200  | V          |
| $V_{GES}$                     | Continuous  | $\pm 20$  | V          |
| $V_{GEM}$                     | Transient   | $\pm 30$  | V          |
| $I_{C25}$                     | $T_C = 25^\circ C$  | 175   | A          |
| $I_{C110}$                    | $T_C = 110^\circ C$   | 55  | A          |
| $I_{CM}$                      | $T_C = 25^\circ C$ , 1ms  | 350   | A          |
| <b>SSOA</b><br><b>(RBSOA)</b> | $V_{GE} = 15V$ , $T_{VJ} = 125^\circ C$ , $R_G = 5\Omega$<br>Clamped Inductive Load | $I_{CM} = 110$<br>$V_{CE} \leq 0.8 \cdot V_{CES}$ | A          |
| $P_C$                         | $T_C = 25^\circ C$  | 650   | W          |
| $T_J$                         |   | -55 ... +175                                      | $^\circ C$ |
| $T_{JM}$                      |   | 175   | $^\circ C$ |
| $T_{stg}$                     |   | -55 ... +175                                      | $^\circ C$ |
| $T_{SOLD}$                    | Plastic Body for 10s  | 260   | $^\circ C$ |
| <b>Weight</b>                 |   | 4   | g          |

## Features

- Optimized for Low Conduction Losses
- Positive Thermal Coefficient of  $V_{ce(sat)}$
- International Standard Package

## Advantages

- High Power Density
- Low Gate Drive Requirement

## Applications

- Power Inverters
- UPS
- Motor Drives
- SMPS
- PFC Circuits
- Battery Chargers
- Welding Machines
- Lamp Ballasts
- Inrush Current Protector Circuits

| Symbol        | Test Conditions<br>( $T_J = 25^\circ C$ , Unless Otherwise Specified) | Characteristic Values |            |                     |
|---------------|---|-----------------------|------------|---------------------|
|               |   | Min.                  | Typ.       | Max.                |
| $BV_{CES}$    | $I_C = 250\mu A$ , $V_{GE} = 0V$                                      | 1200                  |            | V                   |
| $V_{GE(th)}$  | $I_C = 250\mu A$ , $V_{CE} = V_{GE}$                                  | 4.0                   |            | 6.5 V               |
| $I_{CES}$     | $V_{CE} = V_{CES}$ , $V_{GE} = 0V$<br>$T_J = 150^\circ C$             |                       |            | 5 $\mu A$<br>2.5 mA |
| $I_{GES}$     | $V_{CE} = 0V$ , $V_{GE} = \pm 20V$                                    |                       |            | $\pm 100$ nA        |
| $V_{CE(sat)}$ | $I_C = 55A$ , $V_{GE} = 15V$ , Note 1<br>$T_J = 150^\circ C$          |                       | 1.5<br>1.8 | V<br>V              |

| Symbol Test Conditions<br>( $T_J = 25^\circ\text{C}$ Unless Otherwise Specified) |   | Characteristic Values |      |           |
|--|---|-----------------------|------|-----------|
|  |   | Min.                  | Typ. | Max.      |
| $g_{fs}$   | $I_C = 55\text{A}, V_{CE} = 10\text{V}$ , Note 1  | 22                    | 36   | S         |
| $C_{ies}$  | } $V_{CE} = 25\text{V}, V_{GE} = 0\text{V}, f = 1\text{MHz}$  |                       | 2150 | pF        |
| $C_{oes}$  |   |                       | 125  | pF        |
| $C_{res}$  |   |                       | 80   | pF        |
| $Q_{g(on)}$  | } $I_C = 55\text{A}, V_{GE} = 15\text{V}, V_{CE} = 0.5 \cdot V_{CES}$   |                       | 110  | nC        |
| $Q_{ge}$   |   |                       | 17   | nC        |
| $Q_{gc}$   |   |                       | 56   | nC        |
| $t_{d(on)}$  | } <b>Inductive load, <math>T_J = 25^\circ\text{C}</math></b><br>$I_C = 40\text{A}, V_{GE} = 15\text{V}$<br>$V_{CE} = 0.5 \cdot V_{CES}, R_G = 5\Omega$<br>Note 2  |                       | 23   | ns        |
| $t_{ri}$   |   |                       | 35   | ns        |
| $E_{on}$   |   |                       | 2.3  | mJ        |
| $t_{d(off)}$   |   |                       | 300  | ns        |
| $t_{fi}$   |   |                       | 270  | ns        |
| $E_{off}$  |   |                       | 5.3  | mJ        |
| $t_{d(on)}$  | } <b>Inductive load, <math>T_J = 150^\circ\text{C}</math></b><br>$I_C = 40\text{A}, V_{GE} = 15\text{V}$<br>$V_{CE} = 0.5 \cdot V_{CES}, R_G = 5\Omega$<br>Note 2 |                       | 21   | ns        |
| $t_{ri}$   |   |                       | 33   | ns        |
| $E_{on}$   |   |                       | 3.8  | mJ        |
| $t_{d(off)}$   |   |                       | 380  | ns        |
| $t_{fi}$   |   |                       | 530  | ns        |
| $E_{off}$  |   |                       | 8.8  | mJ        |
| $R_{thJC}$   |   |                       |      | 0.23 °C/W |

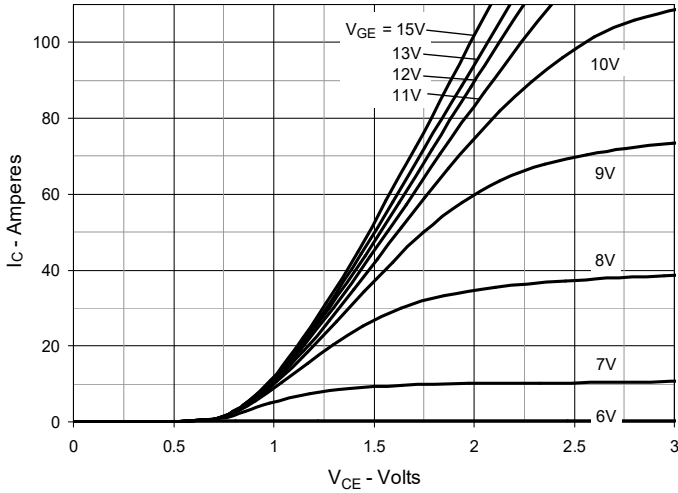
**Notes:**

1. Pulse test,  $t \leq 300\mu\text{s}$ , duty cycle,  $d \leq 2\%$ .
2. Switching times & energy losses may increase for higher  $V_{CE}(\text{clamp})$ ,  $T_J$  or  $R_G$ .

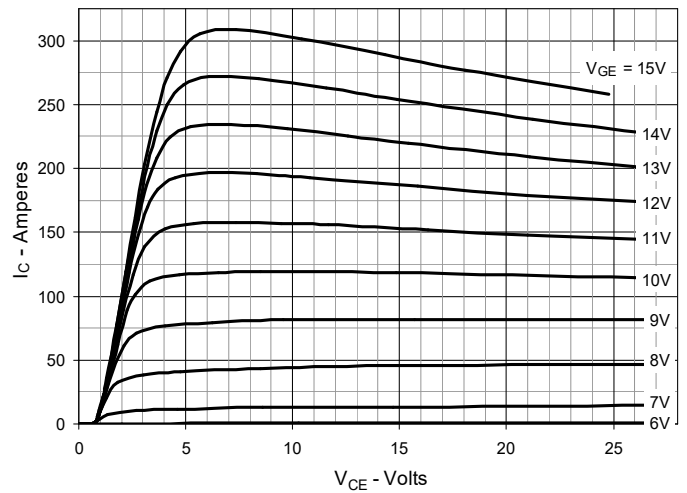
Littelfuse Reserves the Right to Change Limits, Test Conditions, and Dimensions.

|   |           |           |           |           |              |              |              |              |              |             |
|---|-----------|-----------|-----------|-----------|--------------|--------------|--------------|--------------|--------------|-------------|
| IXYS MOSFETs and IGBTs are covered            | 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665    | 6,404,065 B1 | 6,683,344    | 6,727,585    | 7,005,734 B2 | 7,157,338B2 |
| by one or more of the following U.S. patents: | 4,860,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123 B1 | 6,534,343    | 6,710,405 B2 | 6,759,692    | 7,063,975 B2 |             |
|   | 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728 B1 | 6,583,505    | 6,710,463    | 6,771,478 B2 | 7,071,537    |             |

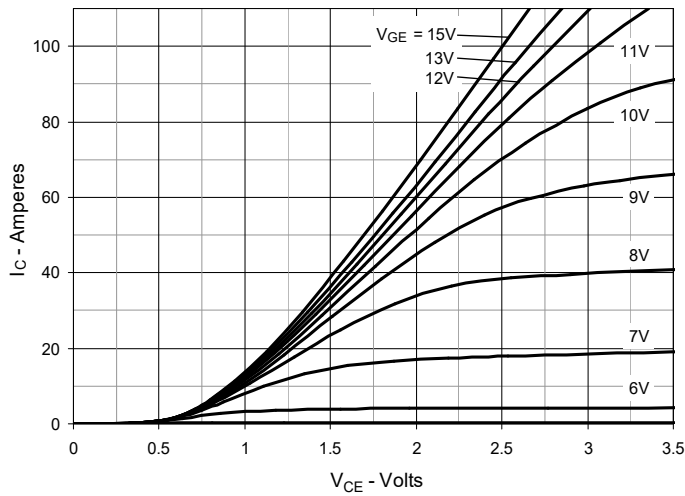
**Fig. 1. Output Characteristics @  $T_J = 25^\circ\text{C}$**



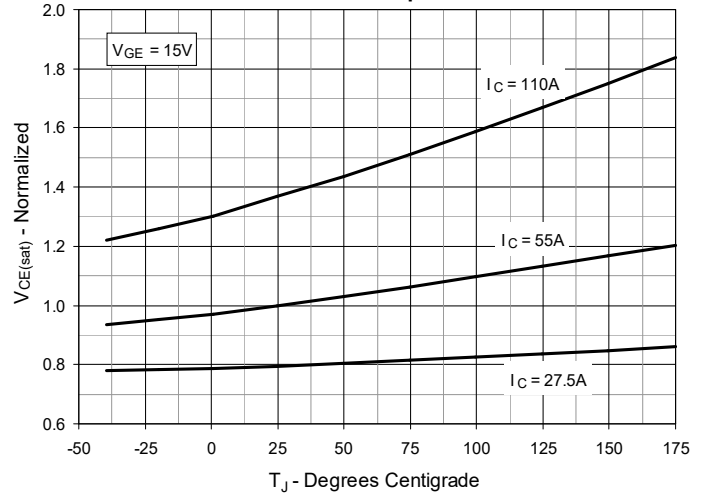
**Fig. 2. Extended Output Characteristics @  $T_J = 25^\circ\text{C}$**



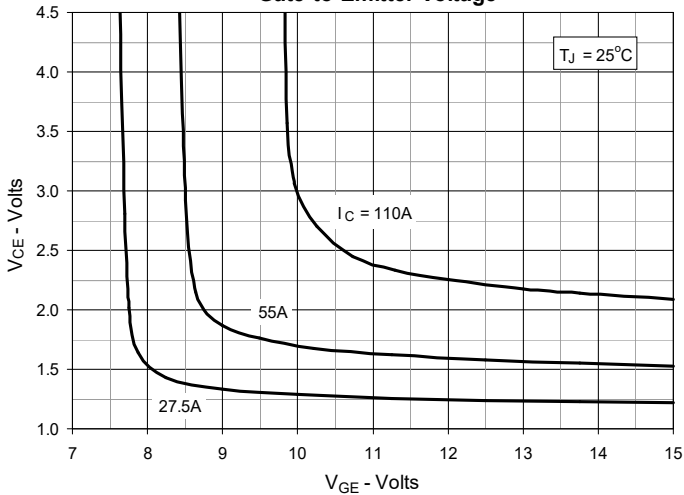
**Fig. 3. Output Characteristics @  $T_J = 150^\circ\text{C}$**



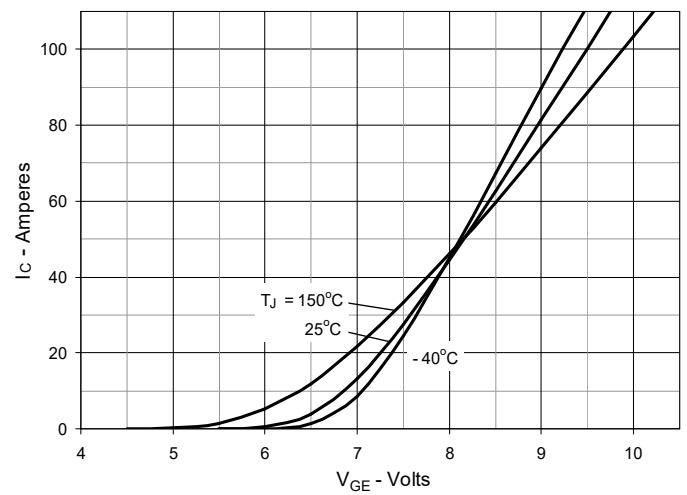
**Fig. 4. Dependence of  $V_{CE(sat)}$  on Junction Temperature**



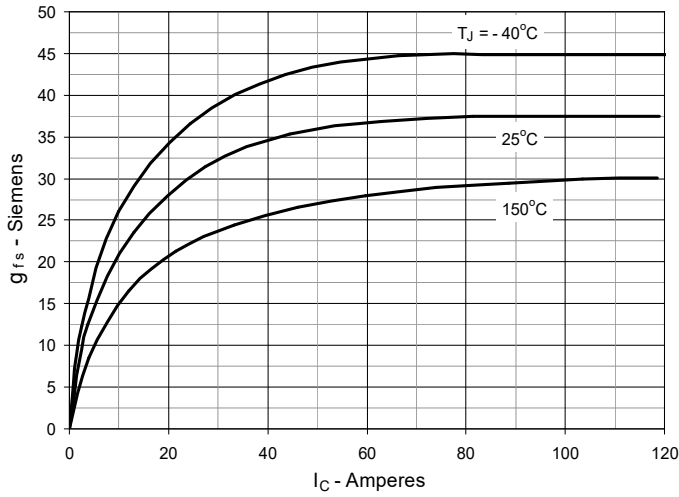
**Fig. 5. Collector-to-Emitter Voltage vs. Gate-to-Emitter Voltage**



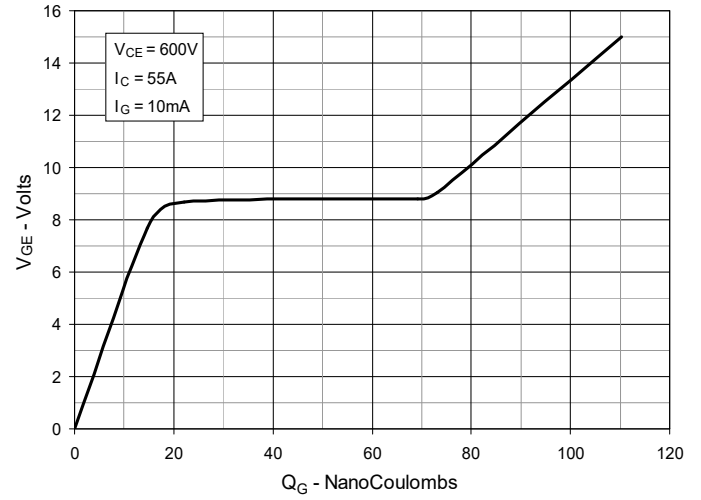
**Fig. 6. Input Admittance**



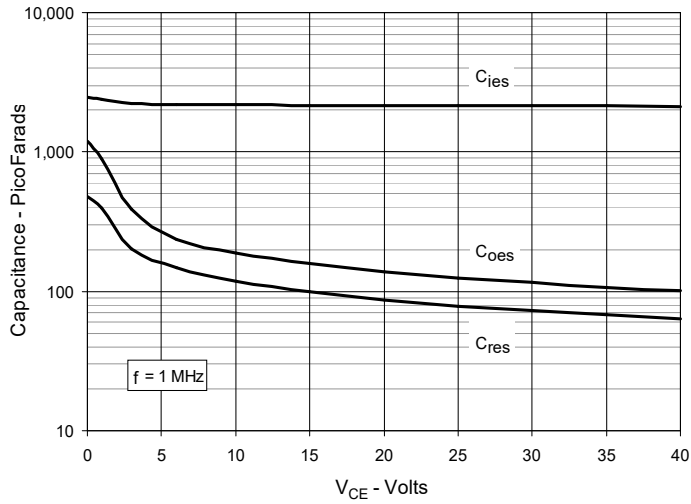
**Fig. 7. Transconductance**



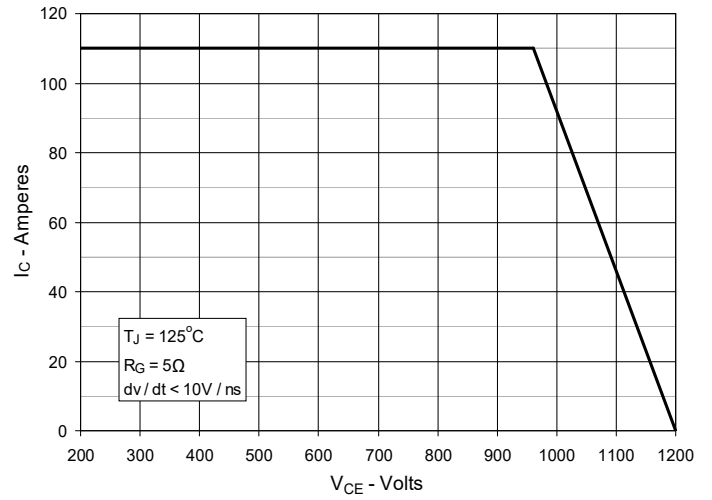
**Fig. 8. Gate Charge**



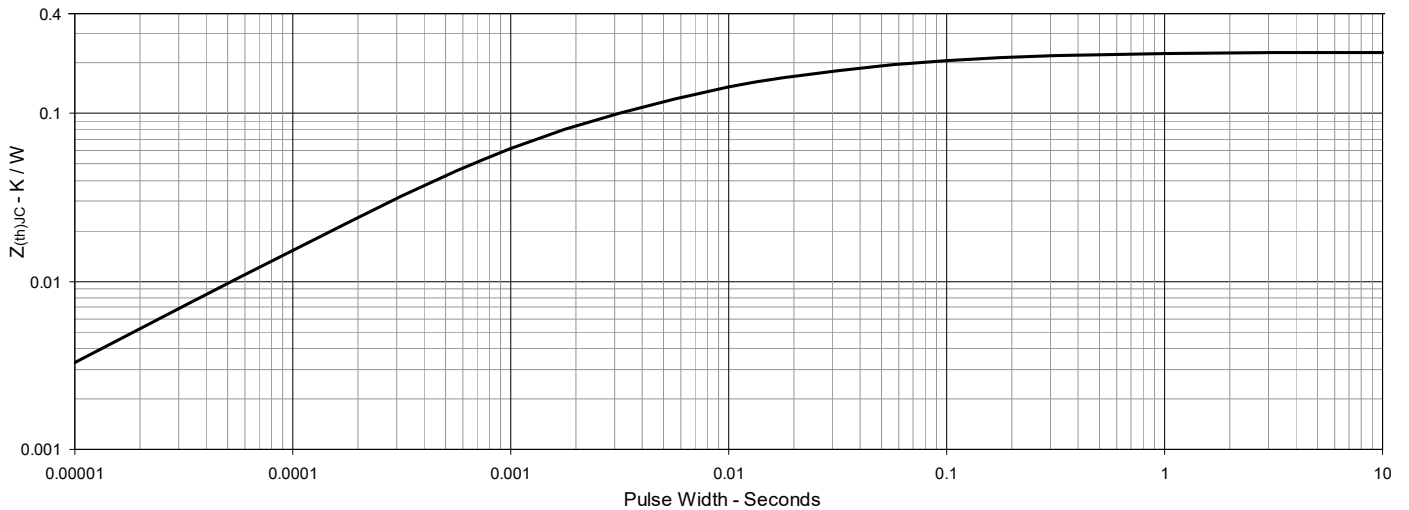
**Fig. 9. Capacitance**



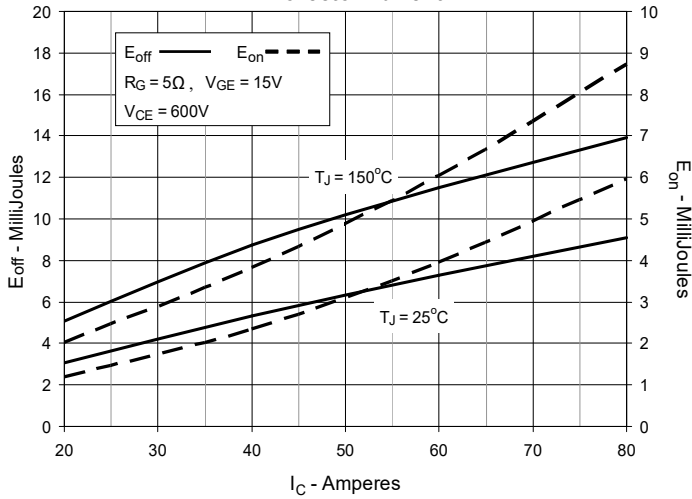
**Fig. 10. Reverse-Bias Safe Operating Area**



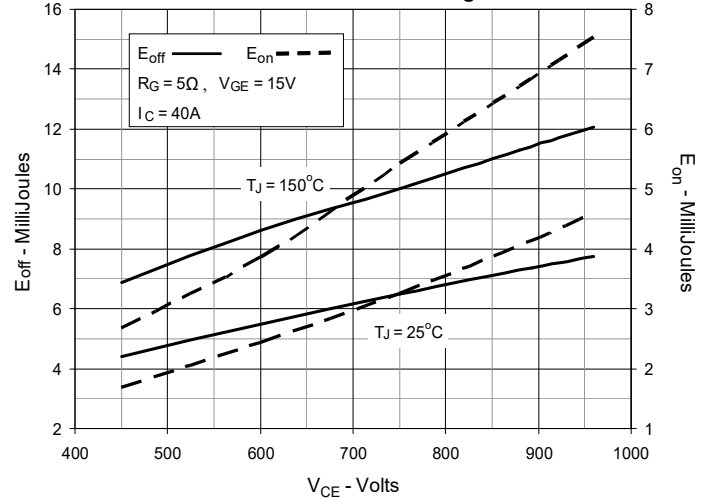
**Fig. 11. Maximum Transient Thermal Impedance**



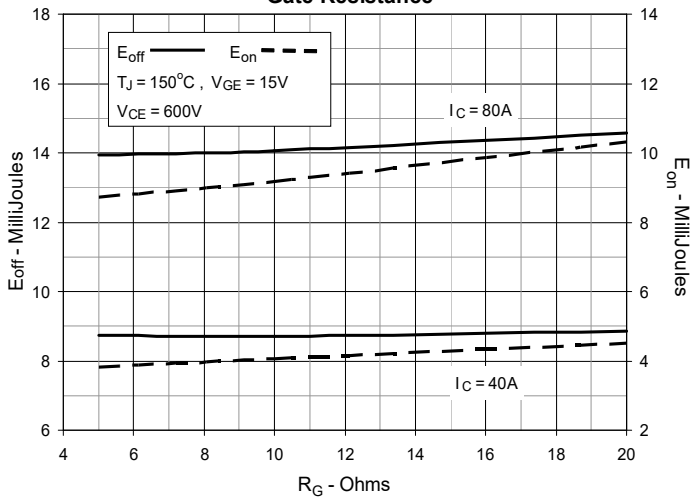
**Fig. 12. Inductive Switching Energy Loss vs. Collector Current**



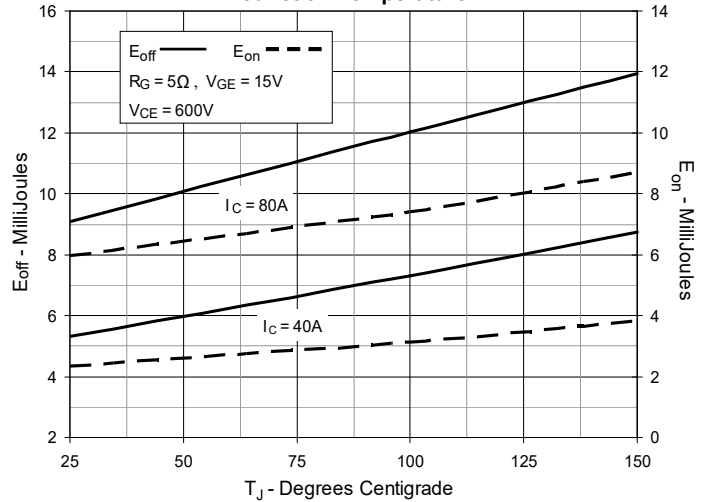
**Fig. 13. Inductive Switching Energy Loss vs. Collector-Emitter Voltage**



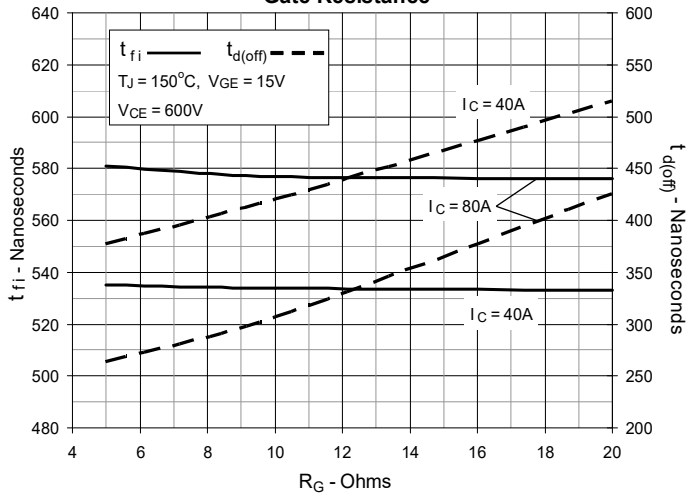
**Fig. 14. Inductive Switching Energy Loss vs. Gate Resistance**



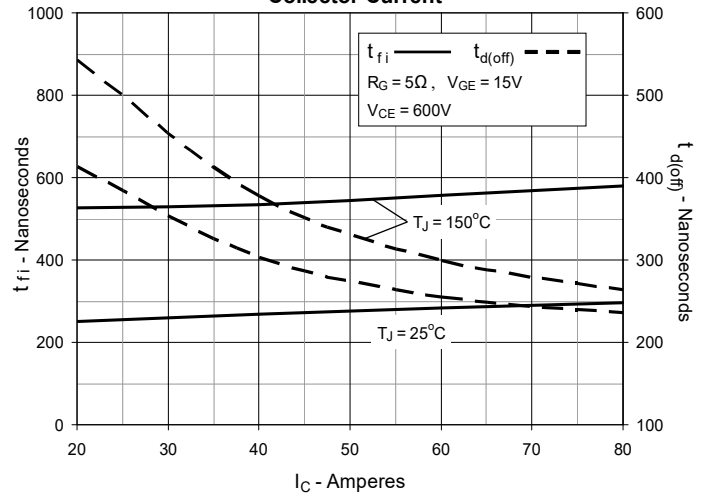
**Fig. 15. Inductive Switching Energy Loss vs. Junction Temperature**



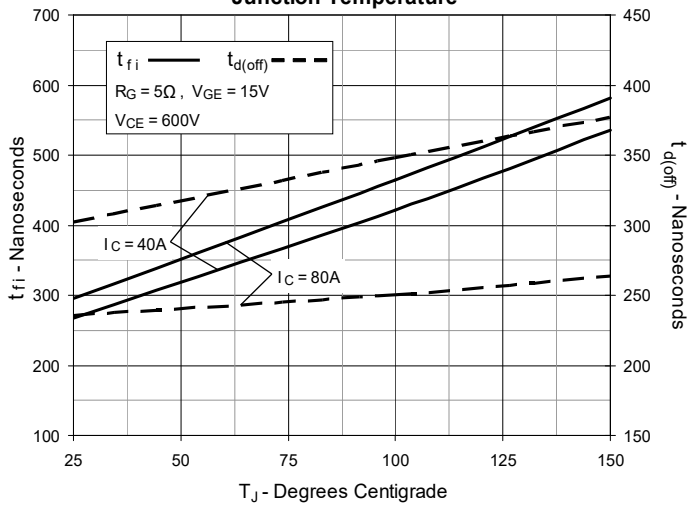
**Fig. 16. Inductive Turn-off Switching Times vs. Gate Resistance**



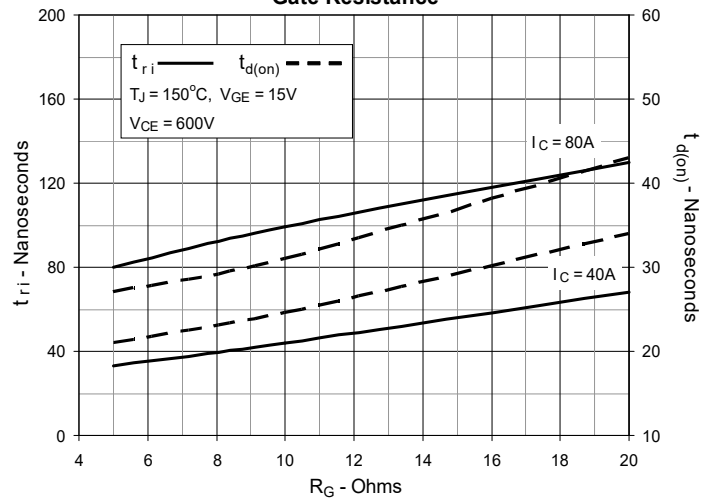
**Fig. 17. Inductive Turn-off Switching Times vs. Collector Current**



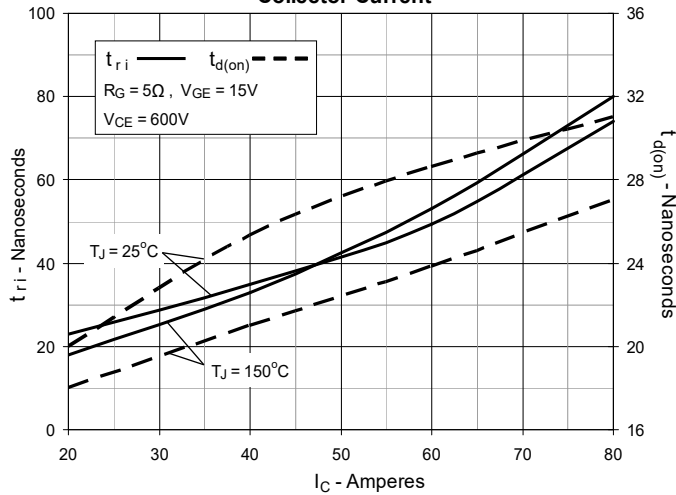
**Fig. 18. Inductive Turn-off Switching Times vs. Junction Temperature**



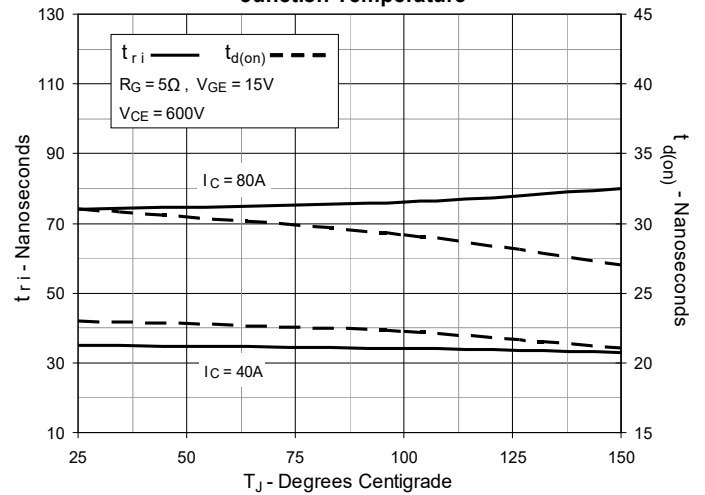
**Fig. 19. Inductive Turn-on Switching Times vs. Gate Resistance**

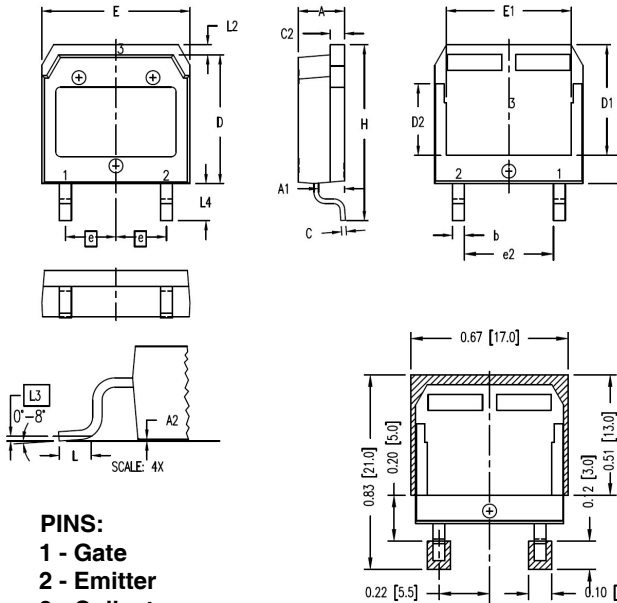


**Fig. 20. Inductive Turn-on Switching Times vs. Collector Current**



**Fig. 21. Inductive Turn-on Switching Times vs. Junction Temperature**



**TO-268HV Outline**


**PINS:**  
**1 - Gate**  
**2 - Emitter**  
**3 - Collector**

| SYM  | INCHES   |      | MILLIMETER |       |
|------|----------|------|------------|-------|
|      | MIN      | MAX  | MIN        | MAX   |
| A    | .193     | .201 | 4.90       | 5.10  |
| A1   | .106     | .114 | 2.70       | 2.90  |
| A2   | .001     | .010 | 0.02       | 0.25  |
| b    | .045     | .057 | 1.15       | 1.45  |
| C    | .016     | .026 | 0.40       | 0.65  |
| C2   | .057     | .063 | 1.45       | 1.60  |
| D    | .543     | .551 | 13.80      | 14.00 |
| D1   | .465     | .476 | 11.80      | 12.10 |
| D2   | .295     | .307 | 7.50       | 7.80  |
| D3   | .114     | .126 | 2.90       | 3.20  |
| E    | .624     | .632 | 15.85      | 16.05 |
| E1   | .524     | .535 | 13.30      | 13.60 |
| e    | .215 BSC |      | 5.45 BSC   |       |
| (e2) | .374     | .386 | 9.50       | 9.80  |
| H    | .736     | .752 | 18.70      | 19.10 |
| L    | .067     | .079 | 1.70       | 2.00  |
| L2   | .039     | .045 | 1.00       | 1.15  |
| L3   | .010 BSC |      | 0.25 BSC   |       |
| L4   | .150     | .161 | 3.80       | 4.10  |



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